NSN 5961-00-177-3577

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Inclosure Material:

Plastic

Overall Length:

0.450 inches

Overall Height:

0.130 inches

Overall Width:

0.330 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

8.0 breakdown voltage, collector-to-base, emitter open and 5.0 breakdown voltage, emitter-to-base, collector open and 80.0 breakdown voltage, collector-to-emitter, base open

Current Rating Per Characteristic:

1.00 amperes source cutoff current and 1.00 amperes source cutoff current

Power Rating Per Characteristic:

30.0 watts small-signal input power, common-collector

Transfer Ratio:

150.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

3 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0